NSN 5961-01-537-6691

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-537-6691 **Inclosure Material:** Glass **Overall Length:** 1.650 inches **End Application:** 0a-923 (v) /g, operations group fixed **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 116.0 breakdown voltage, dc and 94.0 working peak reverse voltage **Current Rating Per Characteristic:** 1.00 milliamperes forward current, average peak **Product Name:** Semiconductor device assembly **Special Features:** Semiconductor device diode 1n6064a, 2 terminal lug crimp type. Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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